p Attorney's Docket No.: 042390P10625

Patent Pacel

C.F.R. § 1.116

DIRE

1925

Art Unit: 2825

RESPONSE UNDER 37 C.F.R. § 1.116 EXPEDITED PROCEDURE EXAMINING GROUP 2825

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re F	Patent Application of:	
	Jack Hwang, et al.))) Examiner: Igwe U. Anya
Application No.: 09/887,910) Art Unit: 2825
Filed:	June 22, 2001) Art Offit. 2823
For:	A METHOD OF MAKING A SEMICONDUCTOR TRANSISTOR BY IMPLANTING IONS INTO A GATE DIELECTRIC LAYER THEREOF))))
Comm	top AF nissioner for Patents ox 1450 ndria, VA 22313-1450	
	RESPONSE AFTER FINAL ACTION U	NDER 37 C.F.R. § 1.116
Dear S	Sir:	
	In response to the Final Office Action maile	d on August 20, 2003, Applicant
respec	tfully requests that the Examiner reconsider	the application in light of the
follow	ing remarks.	
****	FIRST CLASS CERTIFICATE (OF MAILING
first-cla	y certify that this correspondence is being deposited v ss mail with sufficient postage in an envelope addres , Washington, D.C., 20231 on:	
	October 17, 2003	
	Date of Deposit	
Linda K. Brost Name of Person Mailing Correspondence		
(Gluda K. Broat	October 17, 2003
	Signature	Date
Jack Hw	ang, et al.	Examiner: Igwe U. Anya

-1-

Serial No.: 09/887,910